

ACCUTEC

MICROCIRCUIT CORPORATION

DESCRIPTION

The Accutec AK5322048WP high density memory module is a CMOS dynamic RAM organized in 2048 x 32 bit words. The module consists of sixteen standard 1 Meg x 4 DRAMs in plastic SOJ packages. The assembly has 8 drams mounted on each side of a printed circuit board in a 72 pad leadless SIM configuration.

This configuration allows socket-mounting of large quantities of memory in applications where high density and ease of inserting additional memory are important.

The operation of the AK5322048 is identical to sixteen 1Meg x 4 Drams. There are four $\overline{\text{CAS}}$ lines and four $\overline{\text{RAS}}$ lines. On each bank of 1Meg x 32, independent byte control is accomplished by the four $\overline{\text{CAS}}$ lines, where each separate $\overline{\text{CAS}}$ line controls two 1Meg x 4 Drams. Two banks of 32 bits are controlled by the two pairs of $\overline{\text{RAS}}$ lines. A sixteen bit data path can be produced by connecting DQ_1 to DQ_{17} , DQ_2 to DQ_{18} , and alternately strobing $\overline{\text{RAS}}_0$ with $\overline{\text{RAS}}_1$ and $\overline{\text{RAS}}_2$ with $\overline{\text{RAS}}_3$.

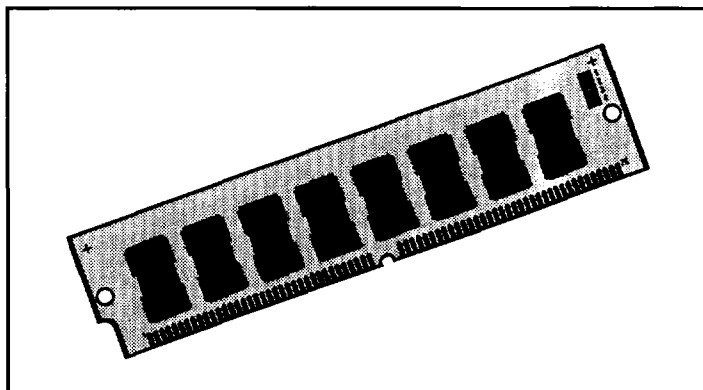
FEATURES

- 2,097,152 x 32 bit organization
- 72 pad Single In-Line Module
- Multiple $\overline{\text{CAS}}$ and $\overline{\text{RAS}}$ lines allow x16 or x32 bit widths
- $\overline{\text{CAS}}$ -before- $\overline{\text{RAS}}$, $\overline{\text{RAS}}$ -only or hidden refresh
- Operating free air temperature 0°C to 70°C
- Single 5 Volt Power Supply
- 2048 Refresh Cycles

AK5322048WP

2,097,152 Word by 32 Bit CMOS

Dynamic Random Access Memory



- Power
 - 5.32 Watt Max Active (60nS)
 - 4.44 Watt Max Active (70 nS)
 - 3.79 Watt Max Active (80 nS)
 - 88 mW Max Standby
- Available in Fast Page Mode and Static Column Mode versions
- Available in leadless SIM or leaded Zip versions
- Downward compatible with AK5321024, AK532512 and AK532256
- Upward compatible with AK5324096 and AK5328192

ADDITIONAL OPTIONS AVAILABLE

- 512K x 32 version, AK532512
- 1 Meg x 32 version, AK5321024

PIN NOMENCLATURE

$\text{DQ}_0 - \text{DQ}_{31}$	Data In/Data Out
$\text{A}_0 - \text{A}_9$	Address Inputs
$\overline{\text{CAS}}_0 - \overline{\text{CAS}}_3$	Column Address Strobe
$\overline{\text{RAS}}_0 - \overline{\text{RAS}}_3$	Row Address Strobe
$\overline{\text{WE}}$	Write Enable
$\text{PD}_1 - \text{PD}_4$	Presence Detect
Vcc	5V Supply
Vss	Ground
NC	No Connect

MODULE OPTIONS

Leadless SIM: AK5322048W

Leaded ZIP: AK5322048Z

PIN ASSIGNMENT

Pin #	Symbol	Pin #	Symbol	Pin #	Symbol	Pin #	Symbol
1	Vss	19	NC	37	NC	55	DQ_{11}
2	DQ_0	20	DQ_4	38	NC	56	DQ_{27}
3	DQ_{16}	21	DQ_{20}	39	Vss	57	DQ_{12}
4	DQ_1	22	DQ_5	40	$\overline{\text{CAS}}_0$	58	DQ_{28}
5	DQ_{17}	23	DQ_{21}	41	$\overline{\text{CAS}}_2$	59	Vcc
6	DQ_2	24	DQ_6	42	$\overline{\text{CAS}}_3$	60	DQ_{29}
7	DQ_{18}	25	DQ_{22}	43	$\overline{\text{CAS}}_1$	61	DQ_{13}
8	DQ_3	26	DQ_7	44	$\overline{\text{RAS}}_0$	62	DQ_{30}
9	DQ_{19}	27	DQ_{23}	45	$\overline{\text{RAS}}_1$	63	DQ_{14}
10	Vcc	28	A7	46	NC	64	DQ_{31}
11	NC	29	NC	47	$\overline{\text{WE}}$	65	DQ_{15}
12	A0	30	Vcc	48	NC	66	NC
13	A1	31	A8	46	DQ_8	67	PD1
14	A2	32	A9	50	DQ_{24}	68	PD2
15	A3	33	$\overline{\text{RAS}}_3$	51	DQ_9	69	PD3
16	A4	34	$\overline{\text{RAS}}_2$	52	DQ_{25}	70	PD4
17	A5	35	NC	53	DQ_{10}	71	NC
18	A6	36	NC	54	DQ_{26}	72	Vss

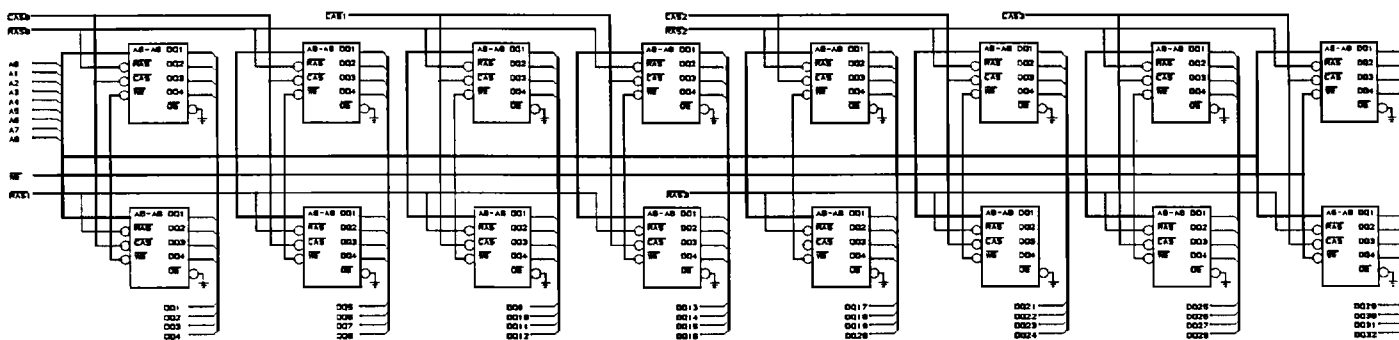
Presence Detect - 1 Meg x 32

	-60	-70	-80
PD1	Vss	Vss	Vss
PD2	Vss	Vss	Vss
PD3	NC	Vss	NC
PD4	NC	NC	Vss

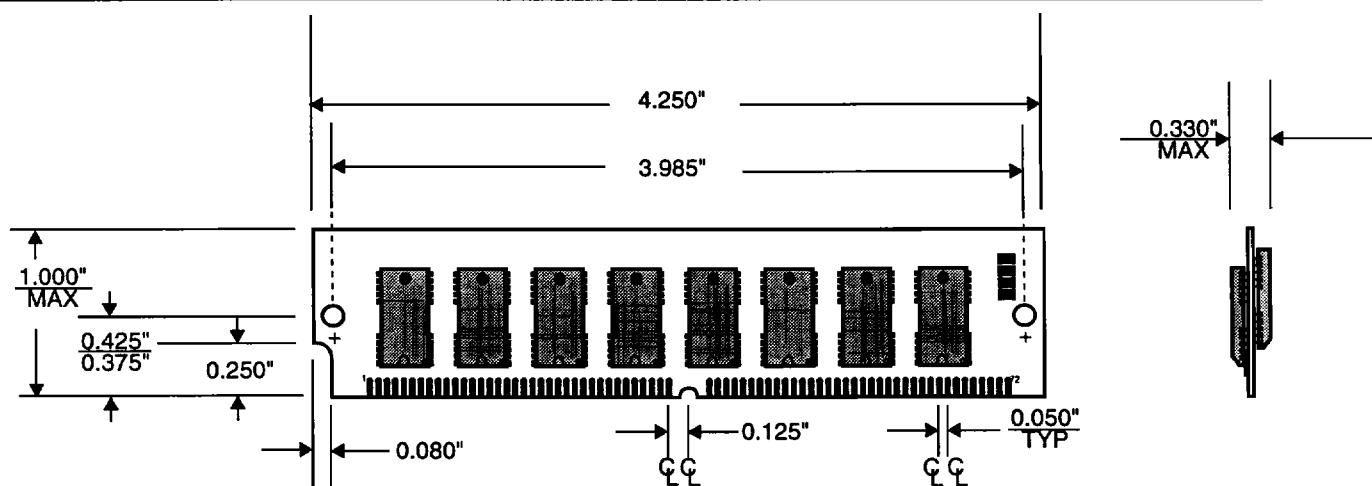
Presence Detect - 2 Meg x 32

	-60	-70	-80
PD1	NC	NC	NC
PD2	NC	NC	NC
PD3	NC	Vss	NC
PD4	NC	NC	Vss

FUNCTIONAL DIAGRAM



MECHANICAL DIMENSIONS



ORDER INFORMATION

PART NUMBER CODING INTERPRETATION

Position 1 2 3 4 5 6 7 8

1 Product

AK = Accuthek Memory

2 Type

4 = Dynamic RAM
5 = CMOS Dynamic RAM
6 = Static RAM

3 Organization/Word Width

1 = by 1 16 = by 16
4 = by 4 32 = by 32
8 = by 8 36 = by 36
9 = by 9

4 Size/Bits Depth

64 = 64K 4096 = 4 MEG
256 = 256K 8192 = 8 MEG
1024 = 1 MEG 16384 = 16 MEG

Position

1 2 3 4 5 6 7 8

5 Package Type

G = Single In-Line Package (SIP)
S = Single In-Line Module (SIM)
D = Dual In-Line Package (DIP)
W = .050 Inch Pitch Edge Connect
Z = Zig-Zag In-Line Package (ZIP)

6 Special Designation

P = Page Mode
N = Nibble Mode
K = Static Column Mode
W = Write Per Bit Mode
V = Video Ram

7 Separator

- = Commercial 0°C to +70°C
M = Military Equivalent Screened (-55°C to +125°C)
I = Industrial Temperature Tested (-45°C to +85°C)
X = Burned In

8 Speed (first two significant digits)

DRAMS	SRAMS
60 = 60 nS	12 = 12 nS
70 = 70 nS	20 = 20 nS
80 = 80 nS	25 = 25 nS
10 = 100 nS	35 = 35 nS

The numbers and coding on this page do not include all variations available, but are shown as examples of the most widely used variations. Contact Accuthek if other information is required.



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